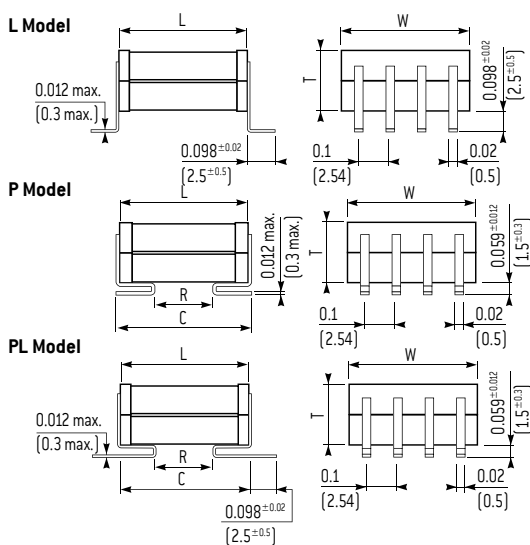
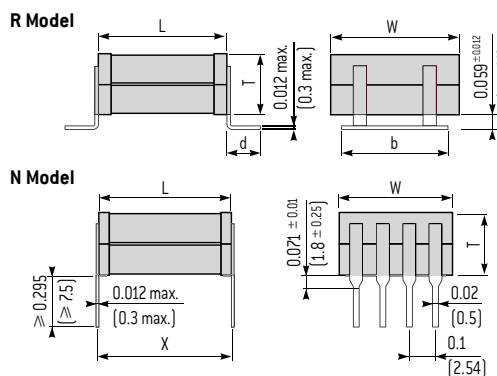


CFS Series

Pulse capacitors with printed resistor option

DIMENSIONS in inches (mm)



STANDARD RATINGS

	Size	2220	2825	3333	4040			
	Exxelia size code	80	81	82	83			
Dimensions inches (mm)	L	0.224 ± 0.020 (5.7 ± 0.5)	0.276 ± 0.020 (7 ± 0.5)	0.331 ± 0.020 (8.4 ± 0.5)	0.400 ± 0.039 (10.16 ± 1)			
	W	0.197 ± 0.020 (5.0 ± 0.5)	0.250 ± 0.020 (6.35 ± 0.5)	0.331 ± 0.020 (8.4 ± 0.5)	0.400 ± 0.039 (10.16 ± 1)			
	d	0.087 ± 0.008 (2.2 ± 0.2)	0.087 ± 0.008 (2.2 ± 0.2)	0.138 ± 0.008 (3.5 ± 0.2)	0.138 ± 0.008 (3.5 ± 0.2)			
	b	0.197 ± 0.020 (5 ± 0.5)	0.197 ± 0.020 (5 ± 0.5)	0.315 ± 0.020 (8 ± 0.5)	0.315 ± 0.020 (8 ± 0.5)			
	R min.	0.098 (2.5)	0.137 (3.5)	0.177 (4.5)	0.275 (7)			
	C max.	0.276 (7)	0.315 (8)	0.355 (9)	0.473 (12)			
	X	0.248 ± 0.020 (6.3 ± 0.5)	0.300 ± 0.020 (7.62 ± 0.5)	0.350 ± 0.020 (8.9 ± 0.5)	0.45 ± 0.020 (11.43 ± 0.5)			
Leads per side		2	2	3	4	T max. inches (mm)	Nb. of chips	
Min. Capacitance value		820pF	1.5nF	2.7nF	6.8nF			
Rated voltage (U _{RC})	1kV	68nF	150nF	390nF	680nF	0.394	(10)	2
		100nF	220nF	560nF	1 μF	0.591	(15)	3
		150nF	270nF	680nF	1.2 μF	0.788	(20)	4
		180nF	390nF	1 μF	1.5 μF	0.985	(25)	5
	1.5kV	33nF	68nF	180nF	270nF	0.394	(10)	2
		47nF	100nF	270nF	390nF	0.591	(15)	3
		68nF	120nF	330nF	560nF	0.788	(20)	4
		82nF	150nF	390nF	680nF	0.985	(25)	5
	2kV	18nF	39nF	68nF	120nF	0.394	(10)	2
		27nF	56nF	100nF	180nF	0.591	(15)	3
		39nF	68nF	150nF	220nF	0.788	(20)	4
		47nF	82nF	180nF	330nF	0.985	(25)	5
	3kV		15nF	33nF	56nF	0.394	(10)	2
			22nF	47nF	82nF	0.591	(15)	3
			33nF	68nF	120nF	0.788	(20)	4
			39nF	82nF	150nF	0.985	(25)	5
	4kV	Consult us			39nF	0.394	(10)	2
					68nF	0.591	(15)	3
					82nF	0.788	(20)	4
					100nF	0.985	(25)	5
	5kV		Consult us	Consult us		0.394	(10)	2
						0.591	(15)	3
						0.788	(20)	4
						0.985	(25)	5
	7.5kV 10kV	-	-	-	Consult us	0.394	(10)	2
		-	-	-		0.591	(15)	3
		-	-	-		0.788	(20)	4
		-	-	-		0.985	(25)	5

Pulse capacitors with printed resistor option

CFS Series

STANDARD RATINGS

	Size	5440	5550	6560	11283	16080		
	Exxelia size code	84	89	85	87	88		
Dimensions inches (mm)	L	0.539 ± 0.039 (13.7 ± 1)	0.551 ± 0.039 (14 ± 1)	0.650 ± 0.039 (16.5 ± 1)	1.122 ± 0.039 (28.5 ± 1)	1.555 ± 0.039 (39.5 ± 1)		
	W	0.400 ± 0.039 (10.16 ± 1)	0.500 ± 0.039 (12.7 ± 1)	0.598 ± 0.039 (15.2 ± 1)	0.827 ± 0.039 (21 ± 1)	0.756 ± 0.039 (19.2 ± 1)		
	d	0.138 ± 0.008 (3.5 ± 0.2)	0.138 ± 0.008 (3.5 ± 0.2)	0.138 ± 0.008 (3.5 ± 0.2)	0.138 ± 0.008 (3.5 ± 0.2)	0.138 ± 0.008 (3.5 ± 0.2)		
	b	0.315 ± 0.020 (8 ± 0.5)	0.315 ± 0.020 (8 ± 0.5)	0.591 ± 0.020 (15 ± 0.5)	0.591 ± 0.020 (15 ± 0.5)	0.591 ± 0.020 (15 ± 0.5)		
	R min.	0.393 (10)	0.393 (10)	0.511 (13)	0.984 (25)	1.377 (35)		
	C max.	0.611 (15.5)	0.63 (16)	0.729 (18.5)	1.26 (32)	1.654 (42)		
	X	0.552 ± 0.020 (14 ± 0.5)	0.563 ± 0.020 (14.3 ± 0.5)	0.7 ± 0.020 (17.78 ± 0.5)	1.15 ± 0.020 (29.21 ± 0.5)	1.6 ± 0.020 (40.64 ± 0.5)		
	Leads per side	4	5	6	6	6	T max. inches (mm)	Nb. of chips
Rated voltage (U _{nc})	Min Capacitance value	6.8nF	12nF	18nF	39nF	47nF		
	1kV	820nF	1.0 µF	1.8 µF	3.9 µF	5.6 µF	0.394 (10)	2
		1.2 µF	1.5 µF	2.7 µF	5.6 µF	8.2 µF	0.591 (15)	3
		1.8 µF	2.2 µF	3.3 µF	8.2 µF	10 µF	0.788 (20)	4
		2.2 µF	2.7 µF	4.7 µF	10 µF	12 µF	0.985 (25)	5
	1.5kV	390nF	470nF	820nF	1.8 µF	2.2 µF	0.394 (10)	2
		560nF	680nF	1.2 µF	2.7 µF	3.3 µF	0.591 (15)	3
		820nF	1 µF	1.5 µF	3.9 µF	4.7 µF	0.788 (20)	4
		1 µF	1.2 µF	1.8 µF	4.7 µF	5.6 µF	0.985 (25)	5
	2kV	180nF	270nF	390nF	1 µF	1.2 µF	0.394 (10)	2
		270nF	330nF	560nF	1.5 µF	1.8 µF	0.591 (15)	3
		390nF	470nF	820nF	1.8 µF	2.7 µF	0.788 (20)	4
		470nF	560nF	1 µF	2.2 µF	3.3 µF	0.985 (25)	5
	3kV	82nF	100nF	180nF	390nF	560nF	0.394 (10)	2
		120nF	150nF	270nF	680nF	820nF	0.591 (15)	3
		150nF	180nF	330nF	820nF	1.2 µF	0.788 (20)	4
		220nF	220nF	470nF	1 µF	1.5 µF	0.985 (25)	5
	4kV	56nF	68nF	100nF	220nF	330nF	0.394 (10)	2
		100nF	100nF	150nF	330nF	470nF	0.591 (15)	3
		120nF	120nF	220nF	470nF	680nF	0.788 (20)	4
		150nF	150nF	270nF	560nF	820nF	0.985 (25)	5
	5kV	33nF	39nF	68nF	150nF	220nF	0.394 (10)	2
		56nF	56nF	100nF	220nF	330nF	0.591 (15)	3
		68nF	82nF	120nF	270nF	390nF	0.788 (20)	4
		82nF	100nF	150nF	390nF	560nF	0.985 (25)	5
	7.5kV	10nF	10nF	22nF	68nF	82nF	0.394 (10)	2
		15nF	15nF	33nF	100nF	120nF	0.591 (15)	3
		18nF	22nF	39nF	120nF	180nF	0.788 (20)	4
		27nF	27nF	56nF	150nF	220nF	0.985 (25)	5
	10kV	5.6nF	5.6nF	12nF	33nF	47nF	0.394 (10)	2
		6.8nF	8.2nF	18nF	47nF	68nF	0.591 (15)	3
		10nF	12nF	22nF	68nF	100nF	0.788 (20)	4
		12nF	15nF	27nF	82nF	120nF	0.985 (25)	5

The high voltage parts may require varnish or encapsulation to prevent surface arcing.

Available capacitance values:

C4xx dielectrics: E6, E12, E24. Specific values upon request.

The above table defines the standard products, other components may be built upon request.

CS Series

High Voltage Stacked Capacitors



FEATURES

- Multilayer chip ceramic capacitors stacked
- NPO, C4xx and X7R dielectrics
- Capacitance range: 220pf to 15 μ F
- Voltage range: 1,000 V_{DC} to 10,000 V_{DC}

PHYSICAL CHARACTERISTICS

CONSTRUCTION

- **P, PL, L models:** DIL leaded uncoated stacked chip capacitors for surface mounting recommended to eliminate thermomechanical stresses.
- **N, NU models:** DIL leaded stacked chip capacitors for through-hole circuits (N: varnished chips, NU: uncoated chips).
- **R, RU models:** Ribbon leaded stacked chip capacitors for surface mounting (R: varnished chips, RU: uncoated chips) recommended to eliminate thermomechanical stresses.

RECOMMENDED FOOTPRINT

See general information on high voltage capacitors (see page 50).

MARKING

Series, capacitance value, tolerance, rated voltage, date code.

ELECTRICAL SPECIFICATIONS

DIELECTRIC	NPO	C4xx	X7R
Dielectric code	1	4	2
Maximum $\Delta C/^{\circ}C$ over temperature range without voltage	NA	NA	$\pm 15\%$
Temperature coefficient	$[0 \pm 30]$ ppm/ $^{\circ}C$	$[-2,200 \pm 500]$ ppm/ $^{\circ}C$	NA
Aging	None	None	$\leq 2.5\%$ per decade hour
Operating temperature	$-55^{\circ}C$ to $+125^{\circ}C$		
Rated voltage (U _{RC})	1,000 V _{DC} to 10,000 V _{DC}	1,000 V _{DC} to 5,000 V _{DC}	1,000 V _{DC} to 10,000 V _{DC}
Dielectric withstanding voltage	1.3 U _{RC}	1.2 U _{RC}	1.2 U _{RC}
Capacitance	at 1MHz for C $\leq$ 1,000pf at 1kHz for C > 1,000pf	at 1kHz	at 1kHz
Dissipation factor	$\leq 0.15\%$ at 1MHz for C $\leq$ 1,000pf $\leq 0.15\%$ at 1kHz for C > 1,000pf	$\leq 0.10\%$ at 1kHz	$\leq 2.5\%$ at 1kHz
Insulation resistance at 25°C under U _{RC} for U _{RC} $\leq$ 500 V under 500 V _{DC} for U _{RC} > 500 V	$\geq 100,000$ M Ω for C $\leq$ 10nf $\geq 1,000$ M Ω μ F for C > 10nf	$\geq 20,000$ M Ω for C $\leq$ 25nf ≥ 500 M Ω μ F for C > 25nf	

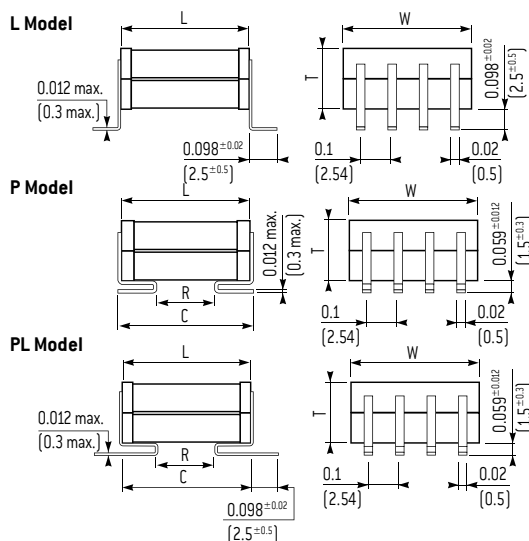
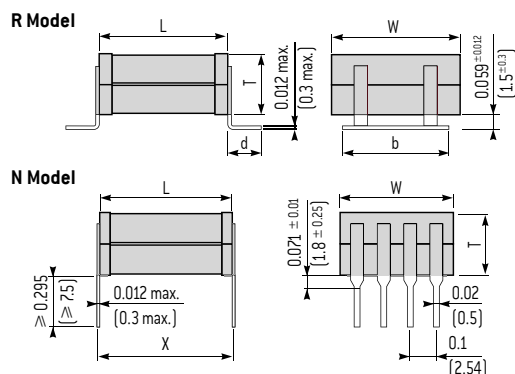
HOW TO ORDER

CS	2	84	P	W	F	120nF	20%	2,000 V	-
Series	Dielectric code	Exxelia size code	Leads style	RoHS compliant	Quality level	Capacitance	Tolerance	Rated voltage	Reliability level
CS = High voltage stacked capacitor	1 = NPO 2 = X7R 4 = C4xx	80 81 82 83 84 89 85 87 88	P PL L R RU N NU	- = No RoHS W = RoHS compliant	- = standard quality level F = Hi-Rel quality: screening in accordance with Exxelia specification	Capacitance value in clear	NPO dielectric: $\pm 1\%$ $\pm 2\%$ $\pm 5\%$ $\pm 10\%$ $\pm 20\%$ C4xx dielectric: $\pm 2\%$ $\pm 5\%$ $\pm 10\%$ $\pm 20\%$ X7R dielectric: $\pm 10\%$ $\pm 20\%$	1,000 V 1,500 V 2,000 V 3,000 V 4,000 V 5,000 V 7,500 V 10,000 V Intermediary, lower and higher voltages available: contact your sales representative.	For F parts only. Acc. to Exxelia spec. - T5 T6 See page 15

High Voltage Stacked Capacitors

CS Series

DIMENSIONS in inches (mm)



STANDARD RATINGS

	Size	2220			2825			3333			4040					
	Exxelia size code	80			81			82			83					
Dimensions inches (mm)	L	0.224 ± 0.020 (5.7 ± 0.5)			0.276 ± 0.020 (7 ± 0.5)			0.331 ± 0.020 (8.4 ± 0.5)			0.400 ± 0.039 (10.16 ± 1)					
	W	0.197 ± 0.020 (5.0 ± 0.5)			0.250 ± 0.020 (6.35 ± 0.5)			0.331 ± 0.020 (8.4 ± 0.5)			0.400 ± 0.039 (10.16 ± 1)					
	d	0.087 ± 0.008 (2.2 ± 0.2)			0.087 ± 0.008 (2.2 ± 0.2)			0.138 ± 0.008 (3.5 ± 0.2)			0.138 ± 0.008 (3.5 ± 0.2)					
	b	0.197 ± 0.020 (5 ± 0.5)			0.197 ± 0.020 (5 ± 0.5)			0.315 ± 0.020 (8 ± 0.5)			0.315 ± 0.020 (8 ± 0.5)					
	R min.	0.098 (2.5)			0.137 (3.5)			0.177 (4.5)			0.275 (7)					
	C max.	0.276 (7)			0.315 (8)			0.355 (9)			0.473 (12)					
	X	0.248 ± 0.020 (6.3 ± 0.5)			0.300 ± 0.020 (7.62 ± 0.5)			0.350 ± 0.020 (8.9 ± 0.5)			0.45 ± 0.020 (11.43 ± 0.5)					
	Leads per side	2			2			3			4					
Dielectric	NPO	C4xx	X7R	NPO	C4xx	X7R	NPO	C4xx	X7R	NPO	C4xx	X7R	T max. inches (mm)		Nb. of chips	
Exxelia ceramic code	1	4	2	1	4	2	1	4	2	1	4	2				
Min. Capacitance value	1nF	3.9nF	12nF	1nF	3.3nF	12nF	1.8nF	5.6nF	22nF	220pF	10nF	27nF				
Rated voltage [U _{dc}]	1kV	12nF	39nF	100nF	18nF	56nF	180nF	39nF	100nF	270nF	68nF	220nF	560nF	0.394	(10)	2
		18nF	68nF	150nF	27nF	82nF	270nF	56nF	150nF	390nF	100nF	330nF	1μF	0.591	(15)	3
		-	-	-	-	-	-	-	-	-	-	-	-	0.788	(20)	4
		-	-	-	-	-	-	-	-	-	-	-	-	0.985	(25)	5
	1.5kV	5.6nF	18nF	39nF	8.2nF	27nF	68nF	22nF	56nF	120nF	39nF	100nF	270nF	0.394	(10)	2
		8.2nF	27nF	56nF	12nF	39nF	100nF	33nF	68nF	180nF	56nF	150nF	390nF	0.591	(15)	3
		-	-	-	-	-	-	-	-	-	-	-	-	0.788	(20)	4
		-	-	-	-	-	-	-	-	-	-	-	-	0.985	(25)	5
	2kV	3.3nF	10nF	22nF	4.7nF	18nF	39nF	8.2nF	27nF	68nF	18nF	56nF	150nF	0.394	(10)	2
		4.7nF	15nF	33nF	6.8nF	27nF	68nF	12nF	39nF	120nF	27nF	82nF	220nF	0.591	(15)	3
		-	-	-	-	-	-	-	-	-	-	-	-	0.788	(20)	4
		-	-	-	-	-	-	-	-	-	-	-	-	0.985	(25)	5
	3kV	2.2nF	4.7nF	12nF	2.7nF	6.8nF	18nF	4.7nF	12nF	33nF	10nF	27nF	68nF	0.394	(10)	2
		3.3nF	6.8nF	18nF	3.9nF	10nF	27nF	6.8nF	22nF	47nF	15nF	39nF	100nF	0.591	(15)	3
		-	-	-	-	-	-	-	-	-	-	-	-	0.788	(20)	4
		-	-	-	-	-	-	-	-	-	-	-	-	0.985	(25)	5
	4kV	1nF	2.7nF	5.6nF	1.8nF	3.3nF	12nF	3.3nF	6.8nF	22nF	5.6nF	15nF	39nF	0.394	(10)	2
		1.5nF	3.9nF	8.2nF	2.7nF	4.7nF	18nF	4.7nF	10nF	33nF	8.2nF	22nF	56nF	0.591	(15)	3
		-	-	-	-	-	-	-	-	-	-	-	-	0.788	(20)	4
		-	-	-	-	-	-	-	-	-	-	-	-	0.985	(25)	5
	5kV	560pF	1.5nF	3.9nF	1.2nF	2.2nF	8.2nF	2.2nF	3.9nF	12nF	3.9nF	8.2nF	27nF	0.394	(10)	2
		820pF	2.7nF	5.6nF	1.8nF	3.3nF	12nF	3.3nF	5.6nF	18nF	5.6nF	12nF	39nF	0.591	(15)	3
		-	-	-	-	-	-	-	-	-	-	-	-	0.788	(20)	4
		-	-	-	-	-	-	-	-	-	-	-	-	0.985	(25)	5
	7.5kV	-	-	-	-	-	-	-	-	-	820pF	-	8.2nF	0.394	(10)	2
		-	-	-	-	-	-	-	-	-	1.2nF	-	12nF	0.591	(15)	3
		-	-	-	-	-	-	-	-	-	-	-	-	0.788	(20)	4
		-	-	-	-	-	-	-	-	-	-	-	-	0.985	(25)	5
	10kV	-	-	-	-	-	-	-	-	-	560pF	-	4.7nF	0.394	(10)	2
		-	-	-	-	-	-	-	-	-	820pF	-	6.8nF	0.591	(15)	3
		-	Due to flashover risks, please consult us for these capacitance values.						-	-	-	-	-	0.788	(20)	4
		-	-	-	-	-	-	-	-	-	-	-	-	0.985	(25)	5

Due to flashover risks, please consult us for these capacitance values.

Selection Guide

Main Characteristic	Model	Size range	Dielectric	Voltage range	Capacitance range	Temperature range	Coating					Leads				Mounting		Main Applications	Page
							Uncoated	Varnished	Conformal coated	Molded	Self protected	DIL	Ribbon	Axial	Radial	SMD	Through hole		
HIGH CAPACITANCE	R SERIES (CHIPS) High Capacitance Chips Capacitors 	2225 to 45107	X7R	50V to 500V	47nF to 27µF	-55°C to +125°C	•									•		Switch Mode Power Supply, filtering, smoothing, decoupling. • aerospace • space • defence	79
	R SERIES (LEADED) Radial Leaded Conformal Coated Capacitors 	-	X7R	50V to 500V	47nF to 27µF	-55°C to +125°C		•							•		•		83
	TEF SERIES Radial Leaded Conformal Coated Capacitors 	-	NPO	63V to 500V	10nF to 680nF	-55°C to +125°C			•						•		•		86
	SV / SC SERIES High Capacitance Stacked Capacitors 	2225 to 125205	X7R	50V to 500V	47nF to 390µF	-55°C to +125°C	•	•				•	•			•	•		87
	CNC3X SERIES High Capacitance Stacked Capacitors 	2220 to 4040	X7R	16V to 25V	1.2µF to 68µF	-55°C to +125°C	•	•				•				•	•		94
	CEC5X SERIES High Capacitance Stacked Capacitors 	3033 to 80150	NPO	63V to 500V	10nF to 6.8µF	-55°C to +125°C	•	•				•				•	•		96
	TEP / TEV SERIES High Capacitance Stacked Capacitors 	-	NPO	63V to 500V	10nF to 6.8µF	-55°C to +125°C		•							•		•		99
HIGH TEMPERATURE	TCN8X SERIES High Capacitance Molded Stacked Capacitors 	-	X7R	63V to 500V	0.47µF to 120µF	-55°C to +125°C				•					•		•	Oil drilling, motor control, braking systems.	101
	CE / CN SERIES High Temperature Chips Capacitors 	0402 to 3040	NPO X7R	16V to 100V	1pF to 8.2µF	-55°C to +250°C	•									•			106
	SCT SERIES High Temperature Stacked Capacitors 	2225 to 125205	X7R	50V to 500V	47nF to 390µF	-55°C to +215°C	•	•				•				•	•		108
	TCE / TCN MOLDED SERIES HT High Temperature Molded Capacitors 	-	NPO X7R	16V to 100V	1pF to 10µF	-55°C to +220°C				•				•	•		•		113
	TCE / TCN SELF-PROTECTED SERIES High Temperature Self-Protected Capacitors 	-	NPO X7R	25V to 500V	10pF to 3.9µF	-55°C to +250°C					•			•	•		•		115
FEED-THRU	TCH SERIES High Temperature High Voltage Capacitors 	-	NPO X7R	200V to 10kV	10pF to 15µF	-55°C to +250°C	•								•		•	Very low ESL	117
	TBC SERIES Discoidal Capacitors 	-	NPO X7R	25V to 1kV	10pF to 12µF	-55°C to +125°C	•									•			121
	BPM SERIES Planar Array 	-	X7R	25V to 200V	330pF to 68nF	-55°C to +125°C	•									•		Very low ESL, miniaturisation	123

Selection Guide

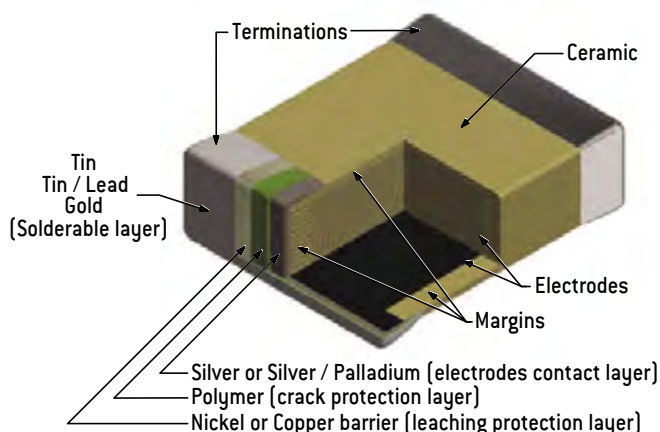
Main Characteristic	Model	Size range	Dielectric	Voltage range	Capacitance range	Temperature range	Coating					Leads				Mounting		Main Applications	Page
							Uncoated	Varnished	Conformal coated	Molded	Self protected	DIL	Ribbon	Axial	Radial	SMD	Through hole		
HIGH Q	XBL SERIES Broadband 	0402	X7R	16V	100nF	-55°C to +125°C	•									•		DC Blocking, Coupling, Bypassing	144
	UBL SERIES Broadband 	0402	X7R	16V	100nF	-55°C to +125°C	•									•			146
	UBZ SERIES Broadband 	0201	X5R X6T	10V	100nF	-55°C to +105°C	•									•			148
	CH SERIES Classic HiQ 	0505 1111	P100	50V to 1.5kV	0.1pF to 1nF	-55°C to +175°C	•						•		•	•		Cellular base station amplifier, MRI.	150
	SH SERIES Super HiQ 	0402 to 1210	NPO	25V to 1.5kV	0.2pF to 1nF	-55°C to +150°C	•						•		•	•		Cellular base station equipment Broadband Point to point/ multi-point radios RF generators	153
	SHD / SHR SERIES Reverse Geometry 	0709 0711	NPO	500V	0.5pF to 100pF	-55°C to +175°C	•									•			156
	NHB SERIES High Self Resonant Frequency 	1111	NPO	500V	0.3pF to 100pF	-55°C to +175°C	•									•			158
	CP SERIES High Power 	2225 4040	P100	200V to 7kV	1pF to 10nF	-55°C to +125°C	•		•				•	•	•	•	•	RF power amplifier Plasma chamber MRI coils	160
	CL SERIES High Power 	2225 to 7065	NPO	200V to 7kV	1pF to 10nF	-55°C to +125°C	•		•				•	•	•	•	•	RF power amplifier Plasma chamber MRI coils	164

ADDITIONAL AVAILABLE RANGES (consult our website)

STANDARD	TCE1X Series 	-	NPO	63V to 100V	0.5pF to 10nF	-55°C to +125°C				•						•		Precision, stability, decoupling	-
	TCN19 Series 	-	2C1	63V to 250V	10pF to 1μF	-55°C to +125°C				•						•		Decoupling	-
	TCN3X Series 	-	2C1	50V to 100V	100pF to 1.8μF	-55°C to +125°C				•						•			-
	LA6 Series 	-	2C1	25V to 63V	100pF to 1μF	-55°C to +125°C				•						•			-
HIGH VOLT.	H Series 	0805 to 6560	NPO X7R	1kV to 10kV	2pF to 390nF	-55°C to +125°C	•		•							•	•	Power supply, voltage multiplier, radars.	-
HIGH CAPACITANCE	CNC5X Series 	3033 to 80150	X7R	63V to 500V	0.1μF to 180μF	-55°C to +125°C	•	•				•				•	•	Switch Mode Power Supply, filtering, smoothing, decoupling. • aerospace • space • defence	-
	CNC8X Series (chips) 	3033 to 33110	X7R	63V to 400V	47nF to 27μF	-55°C to +125°C	•									•			-
	CNC8X Series (DIL) 	3333 to 80150	X7R	63V to 400V	47nF to 180μF	-55°C to +125°C	•	•				•				•	•		-
	TCP / TCV8X Series 	3333 to 80150	X7R	63V to 400V	47nF to 180μF	-55°C to +125°C		•								•	•		-
	TCP / TCV5X Series 	3033 to 80150	X7R	63V to 500V	0.1μF to 180μF	-55°C to +125°C		•								•	•		-
	TCF Series 	-	X7R	63V to 500V	0.1μF to 18μF	-55°C to +125°C			•							•	•		-
HIGH TEMP.	CNC25X Series 	3033 to 5550	X7R	50V	1μF to 33μF	-55°C to +200°C	•	•				•				•	•	Oil drilling, motor control, braking systems.	-
HIGH Q	CNW Series 	-	X7R	100V to 300V	10nF to 1μF	-55°C to +125°C	•						•	•		•	•	Power amplifier	-
	SPT519 / CAW CEW Series 	-	NPO	100V to 300V	10nF to 1μF	-55°C to +125°C	•	•					•	•		•	•		-

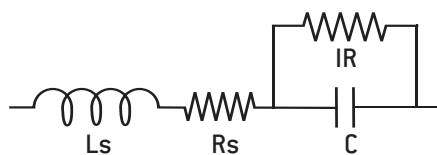
Ceramic Capacitors Technology

MLCC STRUCTURE



EQUIVALENT CIRCUIT

Capacitor is a complex component combining resistive, inductive and capacitive phenomena. A simplified schematic for the equivalent circuit is:



DIELECTRIC CHARACTERISTICS

Insulation Resistance (IR) is the resistance measured under DC voltage across the terminals of the capacitor and consists principally of the parallel resistance shown in the equivalent circuit. As capacitance values and hence the area of dielectric increases, the IR decreases and hence the product $[C \times IR]$ is often specified in $\Omega \cdot F$ or $M\Omega \cdot \mu F$.

The Equivalent Series Resistance (ESR) is the sum of the resistive terms which generate heating when capacitor is used under AC voltage at a given frequency $[f]$.

Dissipation factor (DF) is the ration of the apparent power input will turn to heat in the capacitor:

$$DF = 2\pi f C ESR$$

When a capacitor works under AC voltage, **heat power loss (P)**, expressed in Watt, is equal to:

$$P = 2\pi f C V_{rms}^2 DF$$

The series inductance (Ls) is due to the currents running through the electrodes. It can distort the operation of the capacitor at high frequency where the **impedance (Z)** is given as:

$$Z = R_s + j [L_s \omega - 1/(C \omega)] \text{ with } \omega = 2\pi f$$

When frequency rises, the capacitive component of capacitors is gradually canceled up to the resonance frequency, where :

$$Z = R_s \text{ and } L_s C \omega^2 = 1$$

Above this frequency the capacitor behaves like an inductor.

	P100	NPO	N2200 [C4xx]	BX	2C1	X7R
Dielectric material	Porcelain	Magnesium titanate or Neodynum baryum titanate	Barium zirconate titanate	Baryum titanate [BaTiO ₃]		
Dielectric constant	15 – 18	20 – 85	450	2,000 – 5,000		
Electrode technology	PME (Precious Metal Electrodes): Ag/Pd					
Capacitance variation between –55°C and +125/°C without DC voltage	{100±30}ppm/°C	{0±30}ppm/°C	{–2,200±500}ppm/°C	±15%	±20%	±15%
Capacitance variation between –55°C and +125/°C with DC rated voltage			0 -15%	15% –25%	20% –30%	Not applicable
Piezo-electric effect	None		None	Yes		
Dielectric absorption	None		Few %	Few %		
Thermal shock sensitive	+		+	++		

Ceramic Capacitors Technology

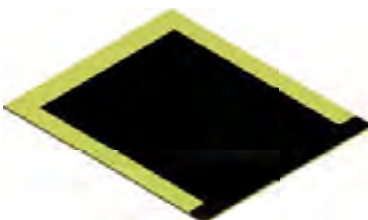
MANUFACTURING STEPS

SLIP CASTING



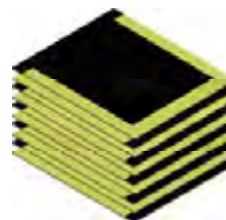
A slurry, a mix of ceramic powder, binder and solvents, is poured onto conveyor belt inside a drying oven, resulting in a dry ceramic sheet.

ELECTRODE SCREEN PRINTING



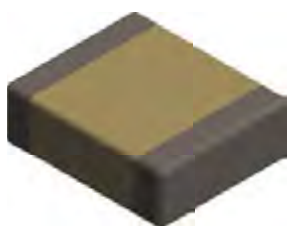
The electrode ink, made from a metal powder mixed with solvents, is printed onto the ceramic sheets using a screen printing process.

STACKING



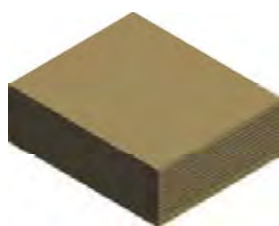
The sheets with electrode printed are stacked to create a multilayer structure.

TERMINATIONS



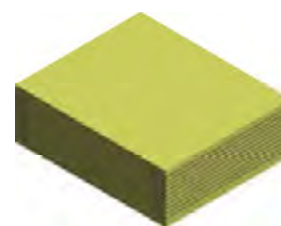
Each terminal of the capacitor is dipped in the termination ink, mix of metal powder, solvents and glass frit and the parts are fired in an oven.

SINTERING



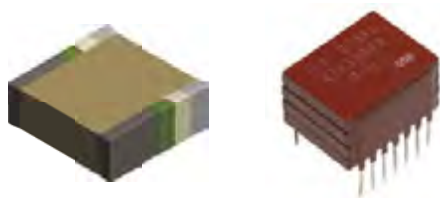
The parts are sintered in an oven with a precise temperature profile which is very important to the characteristics of the capacitors.

PRESSING



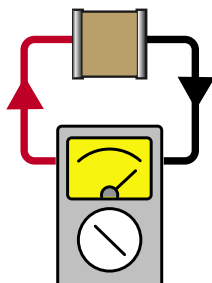
Pressure is applied to the stack to fuse all the separate layers, this created a monolithic structure.

TERMINATIONS PLATING



Stacking + leads soldering + encapsulation
[see pages 10-11]

FINAL TESTING



PACKAGING



User Guide

SMD TERMINATIONS

NON RoHS COMPLIANT	Code	RoHS COMPLIANT	Code	Recommended mounting process							Storage (months)*
Magnetic	Epoxy bonding	Iron soldering	Wave soldering	Vapor phase soldering	Infrared soldering	Wire bonding					
Ag	Q	Ag	QW / P	No	●	●	●	●			18
Ag/Pd/Pt	-	Ag/Pd/Pt	W / A	No	●	●	●				24
Ag/Pd/Pt + dipped Sn/Pb 60/40	H	Ag/Pd/Pt + dipped Sn	HW	No		●					24
Ag + Ni + electrolytic Sn/Pb 95/5	C	Ag + Ni + electrolytic Sn	CW / S	Yes		●	●	●	●		18
Ag + Ni + electrolytic Sn/Pb 60/40	D	-	-	Yes		●	●	●	●		18
-	-	Ag + Cu + electrolytic Sn	C**	No		●	●	●	●		18
Ag + Ni + dipped Sn/Pb 60/40	E	-	-	Yes		●	●				24
Ag + Ni + Au	G	Ag + Ni + Au	GW	Yes	●	●	●	●	●	●	36
Ag + Polymer + Ni + Sn/Pb 95/5	YC	Ag + Polymer + Ni + Sn	YCW	Yes		●	●	●	●		18
Ag + Polymer + Ni + Sn/Pb 60/40	YD	-	-	Yes		●	●	●	●		18
Ag + Polymer + Ni + Au	YG	Ag + Polymer + Ni + Au	YGW	Yes	●	●	●	●	●	●	36

Nickel (Ni) or Copper (Cu) barriers amplify thermal shock and are not recommended for chip sizes larger than 3030.

* Storage must be in a dry environment at a temperature of 20°C with a relative humidity below 50%, or preferably in a package enclosing a desiccant.

** Non magnetic chips series only.

SMD ENVIRONMENTAL TESTS

Ceramic chip capacitors for SMD are designed to meet test requirements of **CECC 32100** and **NF C 93133** standards as specified below in compliance with **NF C 20700** and **IEC 68** standards:

- Solderability: **NF C 20758**, 260°C, bath 62/36/2.
- Adherence: 5N force.
- Vibration fatigue test: **NF C 20706**, 20 g, 10 Hz to 2,000 Hz, 12 cycles of 20 minutes each.
- Rapid temperature change: **NF C 20714**, -55°C to + 125°C, 5 cycles.
- Combined climatic test: **IEC 68-2-38**.
- Damp heat: **NF C 20703**, 93 %, H.R., 40°C.
- Endurance test: 1,000 hours, 1.5 U_{RC}, 125°C.

STORAGE OF CHIP CAPACITORS

TINNED OR NON TINNED CHIP CAPACITORS

Storage must be in a dry environment at a temperature of 20°C with a relative humidity below 50 %, or preferably in a packaging enclosing a desiccant.

STORAGE IN INDUSTRIAL ENVIRONMENT:

- 2 years for tin dipped chip capacitors,
- 18 months for tin electroplated chip capacitors,
- 2 years for non tinned chip capacitors,
- 3 years for gold plated chip capacitors.

STORAGE IN CONTROLLED NEUTRAL NITROGEN ENVIRONMENT:

- 4 years for tin dipped or electroplated chip capacitors,
- 4 years for non tinned chip capacitors,
- 5 years for gold plated chip capacitors.

Storage duration should be considered from delivery date and not from batch manufacture date. The tests carried out at final acceptance stage (solderability, susceptibility to solder heat) enable to assess the compatibility to surface mounting of the chips.

User Guide

LEAD STYLES

SURFACE MOUNTING

DIL LEADS

P style



PL style



L style



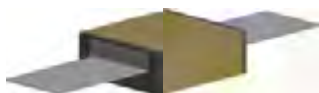
J style



RIBBON LEADS

Micro-strip (type 1)
Short Micro-strip (type 1S)

Axial (Type 2)



Radial (Type 3)



R style



RX style



RJ style



Please contact Exxelia sales for any lead configuration not shown.

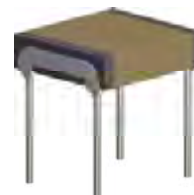
TROUGH-HOLE MOUNTING

AXIAL AND RADIAL

Radial leads (Type 6)



Radial leads (4 leads)



Axial leads (Type 7)



DIL leads: N style



ENCAPSULATION STYLES

Ceramic encapsulation
(selfprotected)

Varnish



Conformal coating

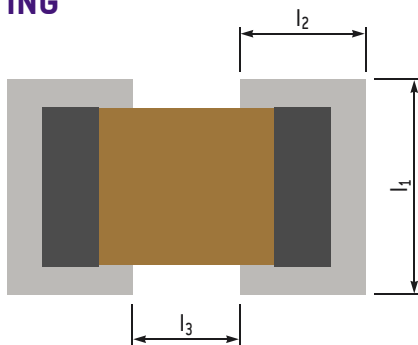


Molding



User Guide

SOLDERING ADVICES FOR REFLOW SOLDERING



Large chips above size 2225 are not recommended to be mounted on epoxy board due to thermal expansion coefficient mismatch between ceramic capacitor and epoxy. Where larger sizes are required, it is recommended to use components with ribbon or other adapted leads so as to absorb thermo-mechanical strains.

Dimensions in inches (in mm)	Reflow soldering						Wave soldering					
	l ₁		l ₂		l ₃		l ₁		l ₂		l ₃	
0402	0.043	(1.1)	0.035	(0.9)	0.012	(0.3)	0.043	(1.1)	0.047	(1.2)	0.012	(0.3)
0403	0.055	(1.4)	0.035	(0.9)	0.012	(0.3)	0.055	(1.4)	0.047	(1.2)	0.012	(0.3)
0504	0.063	(1.6)	0.051	(1.3)	0.016	(0.4)	0.063	(1.6)	0.063	(1.6)	0.016	(0.4)
0603	0.055	(1.4)	0.059	(1.5)	0.02	(0.5)	0.055	(1.4)	0.071	(1.8)	0.02	(0.5)
0805	0.073	(1.85)	0.065	(1.65)	0.024	(0.6)	0.073	(1.85)	0.077	(1.95)	0.024	(0.6)
0907	0.094	(2.4)	0.065	(1.65)	0.035	(0.9)	0.094	(2.4)	0.077	(1.95)	0.035	(0.9)
1005	0.073	(1.85)	0.067	(1.7)	0.039	(1)	0.073	(1.85)	0.079	(2)	0.039	(1)
1206	0.083	(2.1)	0.067	(1.7)	0.059	(1.5)	0.083	(2.1)	0.079	(2)	0.059	(1.5)
1210	0.118	(3)	0.069	(1.75)	0.059	(1.5)	0.118	(3)	0.081	(2.05)	0.059	(1.5)
1605	0.073	(1.85)	0.071	(1.8)	0.087	(2.2)	0.073	(1.85)	0.083	(2.1)	0.087	(2.2)
1806	0.087	(2.2)	0.073	(1.85)	0.102	(2.6)	0.087	(2.2)	0.085	(2.15)	0.102	(2.6)
1812	0.152	(3.85)	0.073	(1.85)	0.102	(2.6)	0.152	(3.85)	0.085	(2.15)	0.102	(2.6)
1825	0.281	(7.15)	0.073	(1.85)	0.102	(2.6)	0.281	(7.15)	0.085	(2.15)	0.102	(2.6)
2210	0.13	(3.3)	0.079	(2)	0.146	(3.7)	0.13	(3.3)	0.091	(2.3)	0.146	(3.7)
2220	0.228	(5.8)	0.079	(2)	0.146	(3.7)	0.228	(5.8)	0.091	(2.3)	0.146	(3.7)
2225	0.281	(7.15)	0.079	(2)	0.146	(3.7)	0.281	(7.15)	0.091	(2.3)	0.146	(3.7)

RECOMMENDED FOOTPRINT FOR SMD CAPACITORS

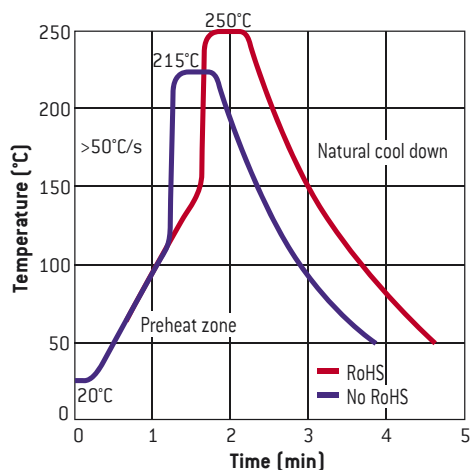
Ceramic is by nature a material which is sensitive both thermally and mechanically. Stresses caused by the physical and thermal properties of the capacitors, substrates and solders are attenuated by the leads.

Wave soldering is unsuitable for sizes larger than 2220 and for the higher ends of capacitance ranges due to possible thermal shock (capacitance values given upon request).

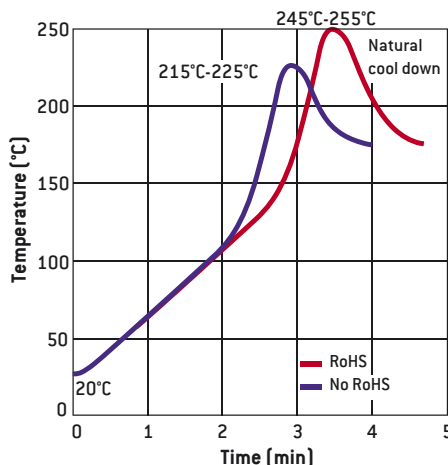
Infrared and vapor phase reflow, are preferred for high reliability applications as inherent thermo-mechanical strains are lower than those inherent to wave soldering.

Whatever the soldering process is, it is highly recommended to apply a thermal cycle, see hereafter our recommended soldering profile:

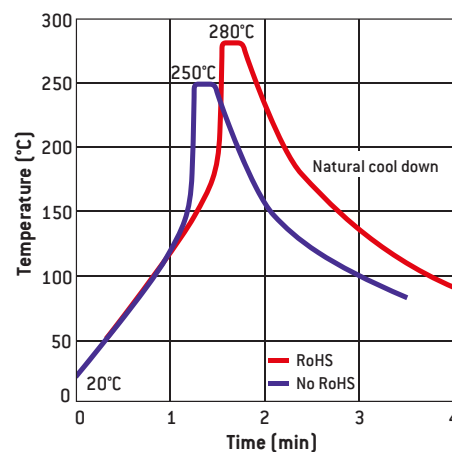
RECOMMENDED VAPOR PHASE REFLOW PROFILE



RECOMMENDED IR REFLOW PROFILE



RECOMMENDED WAVE SOLDERING PROFILE



SOLDERING ADVICES FOR IRON SOLDERING

Attachment with a soldering iron is discouraged due to ceramic brittleness and the process control limitations. In the event that a soldering iron must be used, the following precautions should be observed:

- Use a substrate with chip footprints big enough to allow putting side by side one end of the capacitor and the iron tip without any contact between this tip and the component,
- place the capacitor on this footprint,

- heat the substrate until the capacitor's temperature reaches 150°C minimum (preheating step, maximum 1°C per second),
- place the hot iron tip (a flat tip is preferred) on the footprint **without touching the capacitor**. Use a regulated iron with a 30 watts maximum power. The recommended temperature of the iron is 270 ±10°C. The temperature gap between the capacitor and the iron tip must not exceed 120°C,

User Guide

- leave the tip on the footprint for a few seconds in order to increase locally the footprint's temperature,
- use a cored wire solder and put it down on the iron tip. In a preferred way use Sn/Pb/Ag 62/36/2 alloy,
- wait until the solder fillet is formed on the capacitor's termination,
- take away iron and wire solder,
- wait a few minutes so that the substrate and capacitor come back down to

the preheating temperature,

- solder the second termination using the same procedure as the first,
- let the soldered component cool down slowly to avoid any thermal shock.

PACKAGING

TAPE AND REEL

The films used on the reels correspond to standard IEC 60286-3. Films are delivered on reels in compliance with document IEC 286-3 dated 1991.

Minimum quantity is 250 chips.

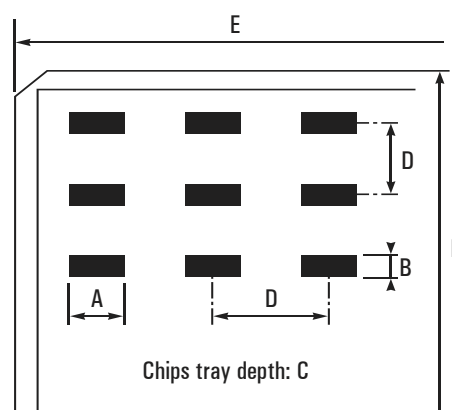
Maximum quantities per reel are as follows:

- Super 8 reel - Ø 180: 2,500 chips.
- Super 8 reel - Ø 330: 10,000 chips.
- Super 12 reel - Ø 180: 1,000 chips.

Reel marking complies with CECC 32100 standard:

- Model.
- Rated capacitance.
- Capacitance tolerance.
- Rated voltage.
- Batch number.

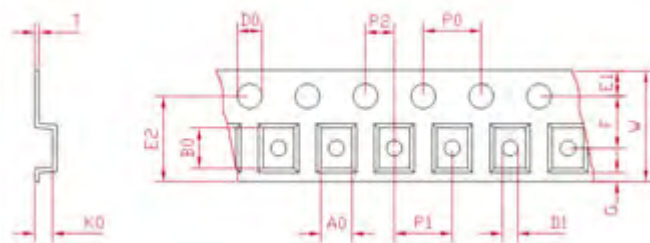
TRAY PACKAGES



DIMENSIONAL CHARACTERISTICS OF CHIPS TRAY PACKAGES

Sizes	Nr. of chips/ package	Oriented chips	Dimensions in inches (in mm)				
			A	B	C	D	E
0402	100	No	0.112 (0.302)		0.065 (1.65)	0.167 (4.24)	2 (50.8)
0403	100	No	0.112 (0.302)		0.065 (1.65)	0.167 (4.24)	2 (50.8)
0504	100	Yes	0.059 (1.5)	0.045 (1.14)	0.035 (0.89)	0.167 (4.24)	2 (50.8)
0603	340	Yes	0.1 (2.54)	0.06 (1.52)	0.045 (1.14)	0.167 (4.24)	2 (50.8)
0805	100	Yes	0.1 (2.54)	0.06 (1.52)	0.045 (1.14)	0.167 (4.24)	2 (50.8)
1206	100	No	0.14 (3.56)	0.14 (3.56)	0.06 (1.52)	0.167 (4.24)	2 (50.8)
1210	100	Yes	0.14 (3.56)	0.14 (3.56)	0.06 (1.52)	0.167 (4.24)	2 (50.8)
1812	100	No	0.25 (6.35)	0.25 (6.35)	0.13 (3.3)	0.345 (8.76)	4 (101.6)
2220	25	Yes	0.24 (6.1)	0.265 (6.73)	0.07 (1.78)	0.345 (8.76)	2 (50.8)
	100	Yes	0.25 (6.35)	0.25 (6.35)	0.13 (3.3)	0.345 (8.76)	4 (101.6)
	25	Yes	0.24 (6.1)	0.265 (6.73)	0.07 (1.78)	0.345 (8.76)	2 (50.8)

HIGH Q CAPACITORS TAPE AND REEL PACKAGING SPECIFICATIONS



Sizes	Type (1)	W±0.3 inches (mm)	F ±0.05 inches (mm)	P1 ±0.1 inches (mm)	T max. inches (mm)	Reel Size inches (mm)	Quantity per Reel
A (0505)	H	0,315 (8)	0,138 (3.5)	0,157 (4)	0,010 (0,25)	7,087 (180)	3'000
A (0505)	V	0,315 (8)	0,138 (3.5)	0,157 (4)	0,010 (0,25)	7,087 (180)	3'000
S (0603)	H	0,315 (8)	0,138 (3.5)	0,157 (4)	0,016 (0,4)	7,087 (180)	4'000
F (0805)	H	0,315 (8)	0,138 (3.5)	0,157 (4)	0,016 (0,4)	7,087 (180)	4'000
B (1111)	H	0,315 (8)	0,138 (3.5)	0,157 (4)	0,012 (0,3)	7,087 (180)	1'000
B (1111)	V	0,315 (8)	0,138 (3.5)	0,157 (4)	0,010 (0,25)	7,087 (180)	1'000
X (2225)	H	0,472 (12)	0,138 (5.5)	0,472 (12)	0,018 (0,45)	12,992 (330)	500
E (4040)	H	0,945 (24)	0,453±0,004 (11.5±0.1)	0,630 (16)	0,018 (0,45)	12,992 (330)	700
E (4040)	V	1,260 (32)	0,559±0,004 (14.2±0.1)	0,945 (24)	0,022 (0,55)	15 (381)	350

(1): Horizontal (H) or Vertical (V) orientation in cavities.

User Guide

EIA STANDARD CAPACITANCE VALUES

Following EIA standard, the values and multiples that are indicated in the chart below can be ordered. E48, E96 series and intermediary values are available upon request.

E6 (± 20%)	E12 (± 10%)	E24 (± 5%)
10	10	10
		11
		12
15	12	13
		15
		16
22	15	18
		20
		22
33	18	24
		27
		30
47	22	33
		36
		39
68	27	43
		47
		51
100	33	56
		62
		68
150	39	75
		82
		91

Voltage (V)	Code	Letter code
25	250	A
40	400	B
50	500	C
63	630	D
100	101	E
200	201	G
250	251	H
400	401	K
500	501	L
1,000	102	M
2,000	202	P
3,000	302	R
4,000	402	S
5,000	502	T
7,500	752	U
10,000	103	W

EIA CAPACITANCE CODE

The capacitance is expressed in three digit codes and in units of pico Farads (pF). The first and second digits are significant figures of the capacitance value and the third digit identifies the multiplier.

For capacitance value < 10pF, R designates a decimal point.

See examples below:

EIA code	Capacitance value		
	in pF	in nF	in µF
2R2	2.2	0.0022	0.0000022
6R8	6.8	0.0068	0.0000068
220	22	0.022	0.000022
470	47	0.047	0.000047
181	180	0.18	0.00018
221	220	0.22	0.00022
102	1,000	1	0.001
272	2,700	2.7	0.0027
123	12,000	12	0.012
683	68,000	68	0.068
124	120,000	120	0.12
564	560,000	560	0.56
335	3,300,000	3,300	3.3
825	8,200,000	8,200	8.2
156	15,000,000	15,000	15
686	68,000,000	68,000	68
107	100,000,000	100,000	100
227	220,000,000	220,000	220

PART MARKING TOLERANCE CODES

Use the following tolerance code chart for part markings:

Tolerance	Letter code
±0.25pF	CU
±0.5pF	DU
±1pF	FU
±1%	F
±2%	G
±5%	J
±10%	K
±20%	M

PART MARKING VOLTAGE CODES

Use the following voltage code chart for part markings: